PCN Numbe	PCN Number: 20231129002.1							:	November 30, 2023		
Title: Qualification of RFAB as an additional Fab site option for select HPA07 devices											
Customer C	Contact:	Chan	ge Manag	Management team Dep			Qual	ity Se	ervices		
Proposed 1	Feb 29,	20 2024 Sam			le reque epted ur		Dec 29, 2023*				
*Sample re	quests i	eceived	after D	ecembe	r 29, 20				orted.		
Change Typ	_										
Assemb				Desig	n			Wafe	r Bump Material		
	ly Proces	s		Data Sheet					r Bump Process		
Assemb	iy Materia	als		Part number change				Wafe	r Fab Site		
Mechani	ical Spec	ification		Test S			Wafe	r Fab Material			
Packing/	/Shipping	J/Labelin	g	Test Process				Wafer Fab Process			
Description	ofChar	0.00.		PCN	l Deta	ls					
-		-	to annoi	ince the	addition		Basana	additi	onal Wafer Fab site		
Texas Instruments is pleased to announce the addition of RFAB as an additional Wafer Fab site option for the products listed in the "Product Affected" section of this document.											
	Curre	nt Fab S	Site				New	Fab	Site		
Current F	ab F	Process		lafer meter		w Fab Site	Pro	oces	s Wafer Diameter		
DP1DM5	;	HPA07	_	0mm		FAB	н	PA07	300mm		
	,	1117(07	20					/(0/	5001111		
Qual details			ne Qual D	ata Sect	ion.						
Reason for	Cha nge:										
Continuity of	f supply										
Anticipated	l impact	on Form	n, Fit, Fu	nction,	Quality	or Relia	ability (	posi	tive / negative):		
None											
Changes to	product	: identif	ication r	esulting	g from t	his PCN	:				
Fab Site Ir											
			e Origin	Code	Chip	Site Cou	untry				
Chip Si	te	•	(20L)		Ċ	ode (211	L) .		Chip Site City		
DP1DM	15		DM5			USA			Dallas		
RFAB			RFB		USA			Richardsor			
Sample prod	Sample product shipping label (not actual product label)										
TEXAS	TS	<b>P</b> 64		(	1P) SN7	4LSO7NS	R				
MADE IN: Mal 2DC:	laysia 20:		<u>111 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1</u>		(a) 200	( D	) 0336				
MSL 2 /260C/			re a tes	() (C	31T)L01	: 39590	47MLA	~			
MSL 1 /235C/ OPT:	UNLIM 03	/29/04	N		4W) IKY P)	(11) 75	2348351	2			
ITEM:	3	, i			2P) REV:	(V) SHF (21L	0033317 ) CC0:USA				
LBL: 5A	(L) IV: I	/50					) ACO: MYS				
						~~					
Product Aff	fected:										
ADS1146IP	146IPW ADS114S			RHBR	ADS	ADS1248IPW			AC7716SPFB		
ADS1146IP	WR	ADS	5114S06I	RHBT	ADS	1248IPW	/R	Г	AC7716SPFBR		
ADS1147IP			5114S08E			124S06E			AC7716SRHAR		
ADS1147IP			5114S08E				BIPBSR		DAC7716SRHAT		
	** 1 \		7100L		703	100L					

ADS1148IPW	ADS114S08BIRHBR	ADS124S06IPBS	DAC8234SPFB
ADS1148IPWR	ADS114S08BIRHBT	ADS124S06IPBSR	DAC8234SPFBR
ADS1148IRHBR	ADS114S08IPBS	ADS124S06IRHBR	DAC8234SRHAR
ADS1148IRHBT	ADS114S08IPBSR	ADS124S06IRHBT	DAC8234SRHAT
ADS114S06BIPBS	ADS114S08IRHBR	ADS124S08BIPBS	DAC8734SPFB
ADS114S06BIPBSR	ADS114S08IRHBT	ADS124S08BIPBSR	DAC8734SPFBR
ADS114S06BIRHBR	ADS1246IPW	ADS124S08IPBS	DAC8734SRHAR
ADS114S06BIRHBT	ADS1246IPWR	ADS124S08IPBSR	DAC8734SRHAT
ADS114S06IPBS	ADS1247IPW	ADS124S08IRHBR	
ADS114S06IPBSR	ADS1247IPWR	ADS124S08IRHBT	

## Qualification Results

## Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: ADS1248IPW	QBS Process Reference: CD3232A1YFFR	QBS Process Reference: CD3232A1YFFR	QBS Process Reference: <u>AMC7836IPAP</u>	QBS Process Reference: INA231AIYFDR	QBS Process Reference: INA231BIYFDR	QBS Process Reference: DRV401AIRGWR
HAST	A2	Biased HAST	130C/85%RH	96 Hours		3/231/0	3/231/0	-	-	-	-
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	-	-	-
тс	A4	Temperature Cycle	-55C/125C	700 Cycles	-	3/231/0	3/231/0	-	-	-	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	-	1/77/0	2/154/0	-
HTOL	В1	Life Test	140C	480 Hours	-	1/77/0	2/154/0	-	-	-	-
HTOL	В1	Life Test	150C	300 Hours		-	-	1/77/0	1/77/0	2/154/0	2/154/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours		1/1000/0	2/2000/0	-	1/1000/0	2/2000/0	-
ESD	E2	ESD CDM	-	1000 Volts	-	3/9/0	-	1/3/0	-	-	2/6/0
ESD	E2	ESD CDM	-	200 Volts		-	-	-	-	-	-
ESD	E2	ESD CDM	-	250 Volts	-	-	-	1/3/0	-	2/6/0	2/6/0

Туре	#	Test Name	Condition	Duration	Qual Device: ADS1248IPW	QBS Process Reference: <u>CD3232A1YFFR</u>	QBS Process Reference: <u>CD3232A1YFFR</u>	QBS Process Reference: <u>AMC7836IPAP</u>	QBS Process Reference: INA231AIYFDR	QBS Process Reference: INA231BIYFDR	QBS Process Reference: <u>DRV401AIRGWR</u>
ESD	E2	ESD CDM	-	350 Volts	-	-	-	-	1/3/0	-	-
ESD	E2	ESD CDM	-	500 Volts	1/3/0						
ESD	E2	ESD HBM	-	1000 Volts	-	3/9/0	3/9/0	-	-	2/6/0	2/6/0
ESD	E2	ESD HBM	-	2500 Volts	-	-	-	1/3/0	-	-	-
ESD	E2	ESD HBM	-	2000 Volts	1/3/0						
ESD	E2	ESD HBM	-	1500 Volts	-	-	-	1/3/0	1/3/0	-	-
LU	E4	LU	Per JESD78	-	-	3/9/0	3/9/0	-	-	-	-
LU	E4	Latch-Up	Per JESD78	-	1/3/0		-	1/3/0	1/6/0	2/12/0	2/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	2/60/0	1/30/0
FTY	E6	Final Test Yield	-	-	1/Pass		-	-	-	-	-

OBS: Oual By Similarity

Oual Device ADS1248IPW is gualified at MSL2 260C

· Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2207-041

[1]-Waiver from CF [2]-Passes room and hot [3]-Passes room and hot

For questions regarding this notice, e-mails can be sent to Change Management team or your local Field Sales Representative.

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